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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: [info@chipsmall.com](mailto:info@chipsmall.com) Web: [www.chipsmall.com](http://www.chipsmall.com)

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



## Asymmetrical Bridge Super Junction MOSFET Power Module

$V_{DSS} = 600V$   
 $R_{DSon} = 24m\Omega \text{ max @ } T_j = 25^\circ C$   
 $I_D = 95A \text{ @ } T_c = 25^\circ C$

### Application

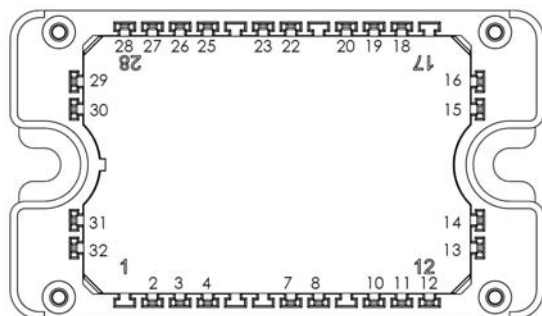
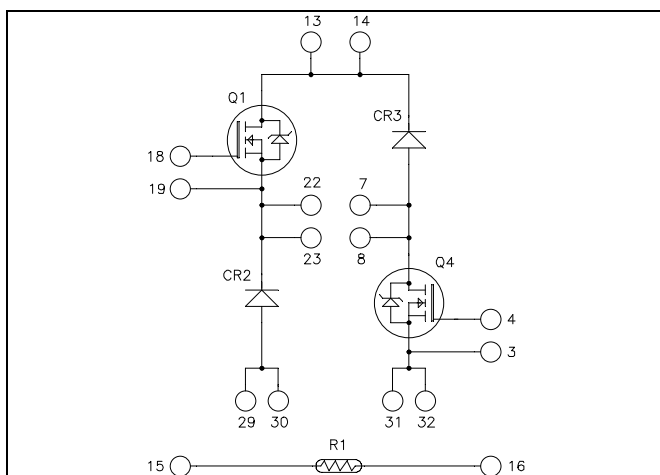
- Welding converters
- Switched Mode Power Supplies
- Switched Reluctance Motor Drives

### Features

- **Super junction MOSFET**
  - Ultra low  $R_{DSon}$
  - Low Miller capacitance
  - Ultra low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS compliant



All multiple inputs and outputs must be shorted together  
 Example: 13/14 ; 29/30 ; 22/23...

**All ratings @  $T_j = 25^\circ C$  unless otherwise specified**

### Absolute maximum ratings (per super junction MOSFET)

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Voltage	600	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
$I_{DM}$	Pulsed Drain current	260	A
$V_{GS}$	Gate - Source Voltage	$\pm 20$	V
$R_{DSon}$	Drain - Source ON Resistance	24	$m\Omega$
$P_D$	Power Dissipation	$T_c = 25^\circ C$	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)	15	A
$E_{AR}$	Repetitive Avalanche Energy	3	mJ
$E_{AS}$	Single Pulse Avalanche Energy	1900	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

## Electrical Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 600V$			350	$\mu A$
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 47.5A$			24	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	2.1	3	3.9	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$			200	nA

## Dynamic Characteristics (per super junction MOSFET)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V; V_{DS} = 25V$ $f = 1MHz$		14.4		nF
$C_{oss}$	Output Capacitance			17		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 300V$ $I_D = 95A$		300		nC
$Q_{gs}$	Gate – Source Charge			68		
$Q_{gd}$	Gate – Drain Charge			102		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive Switching (125°C)</b> $V_{GS} = 10V$ $V_{Bus} = 400V$ $I_D = 95A$ $R_G = 2.5\Omega$		21		ns
$T_r$	Rise Time			30		
$T_{d(off)}$	Turn-off Delay Time			100		
$T_f$	Fall Time			45		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 25°C</b> $V_{GS} = 10V; V_{Bus} = 400V$ $I_D = 95A; R_G = 2.5\Omega$		1350		$\mu J$
$E_{off}$	Turn-off Switching Energy			1040		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ 125°C</b> $V_{GS} = 10V; V_{Bus} = 400V$ $I_D = 95A; R_G = 2.5\Omega$		2200		$\mu J$
$E_{off}$	Turn-off Switching Energy			1270		
$R_{thJC}$	Junction to Case Thermal Resistance				0.27	$^{\circ}C/W$

## Diode ratings and characteristics (per diode)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage				600	V
$I_{RM}$	Reverse Leakage Current	$V_R = 600V$			25	$\mu A$
$I_F$	DC Forward Current	$T_c = 80^{\circ}C$		60		A
$V_F$	Diode Forward Voltage	$I_F = 60A$		1.7	2.3	V
		$I_F = 120A$		2		
		$I_F = 60A, T_j = 125^{\circ}C$		1.4		
$t_{rr}$	Reverse Recovery Time	$I_F = 60A$ $V_R = 400V$	$T_j = 25^{\circ}C$	70		ns
			$T_j = 125^{\circ}C$	140		
$Q_{rr}$	Reverse Recovery Charge	$di/dt = 200A/\mu s$	$T_j = 25^{\circ}C$	100		nC
			$T_j = 125^{\circ}C$	690		
$R_{thJC}$	Junction to Case Thermal Resistance				0.85	$^{\circ}C/W$



## Thermal and package characteristics

Symbol	Characteristic	Min	Max	Unit
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000		V
T <sub>J</sub>	Operating junction temperature range	-40	150	°C
T <sub>JOP</sub>	Recommended junction temperature under switching conditions	-40	T <sub>Jmax</sub> -25	
T <sub>STG</sub>	Storage Temperature Range	-40	125	
T <sub>C</sub>	Operating Case Temperature	-40	125	
Torque	Mounting torque	To heatsink	M4	
Wt	Package Weight		110	g

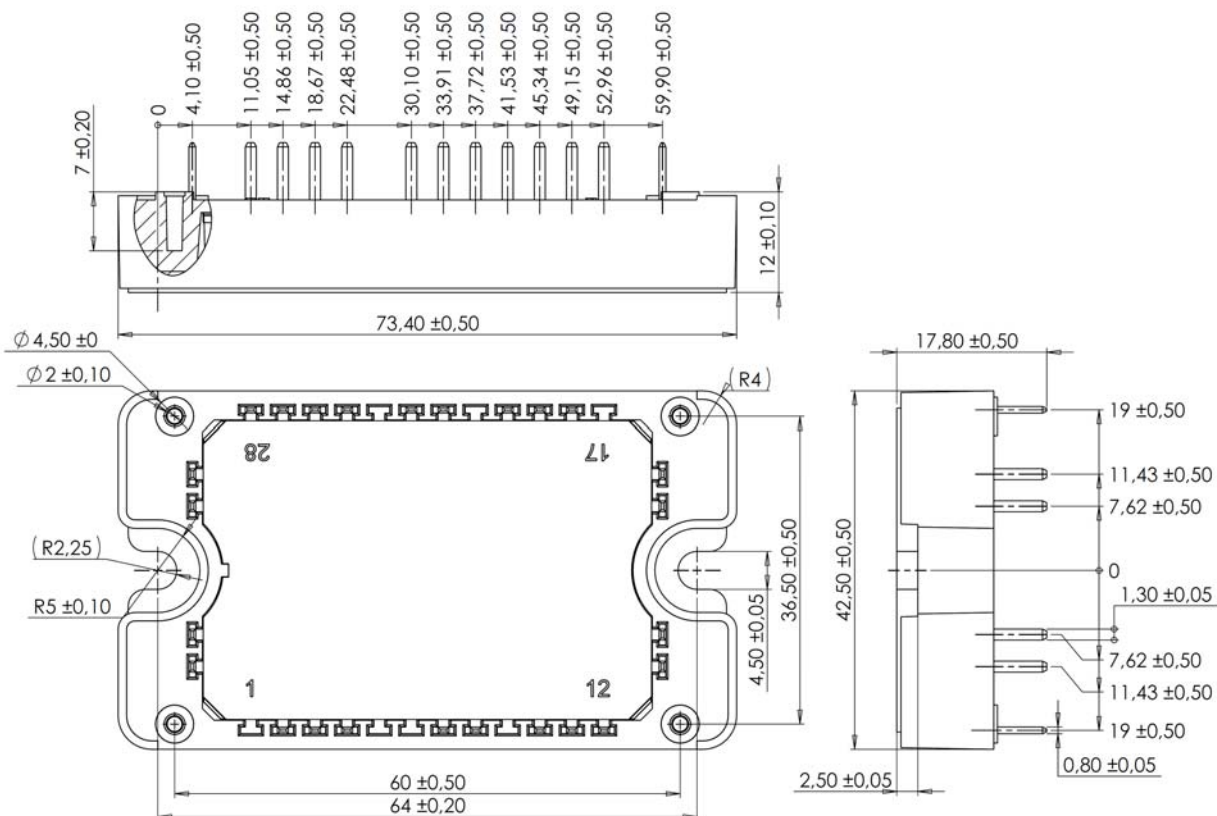
## Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Typ	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
ΔR <sub>25</sub> /R <sub>25</sub>			5		%
B <sub>25/85</sub>	T <sub>25</sub> = 298.15 K		3952		K
ΔB/B	T <sub>C</sub> = 100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$

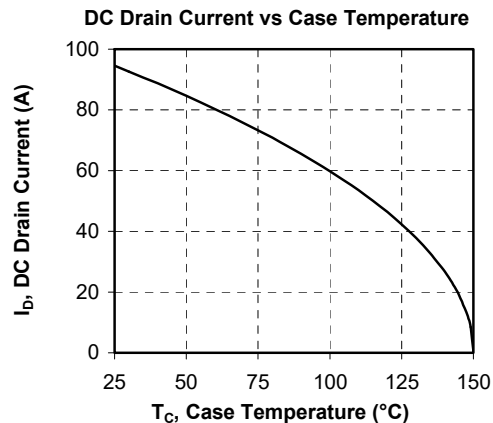
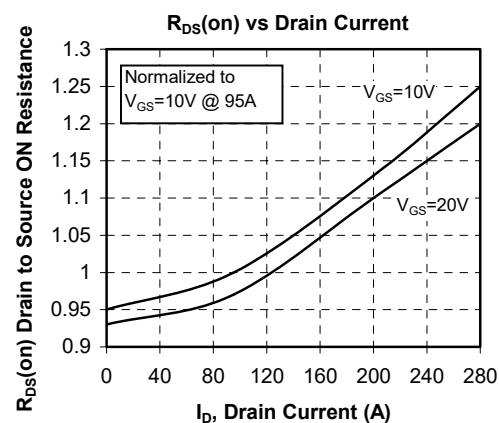
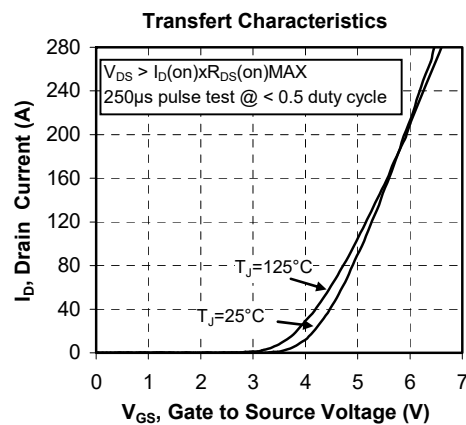
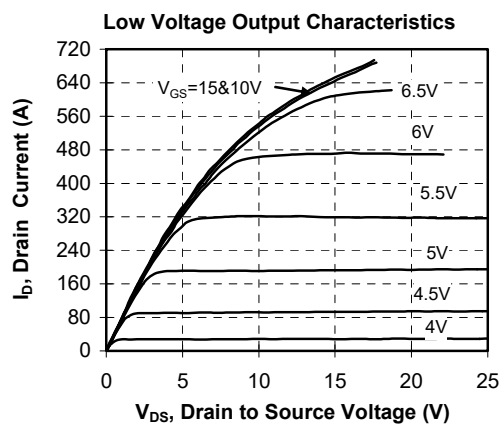
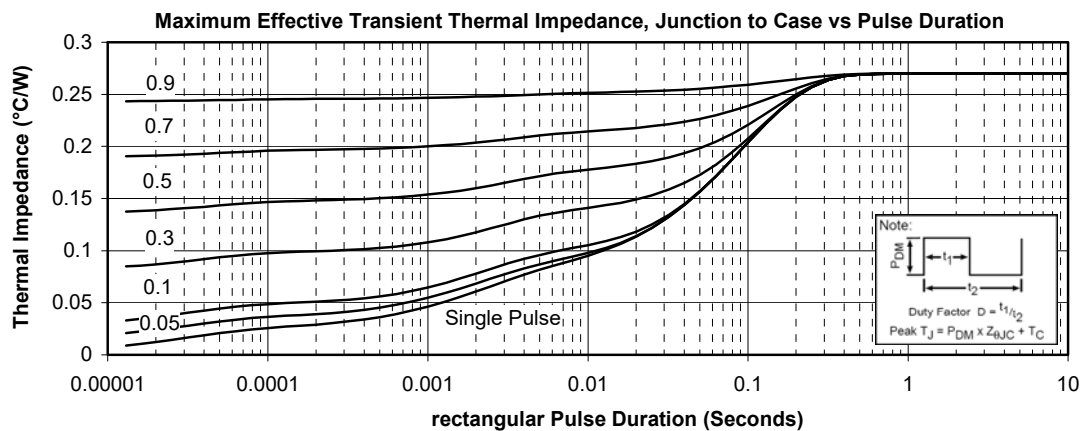
T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

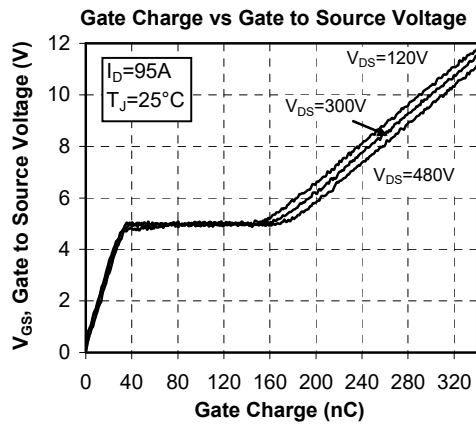
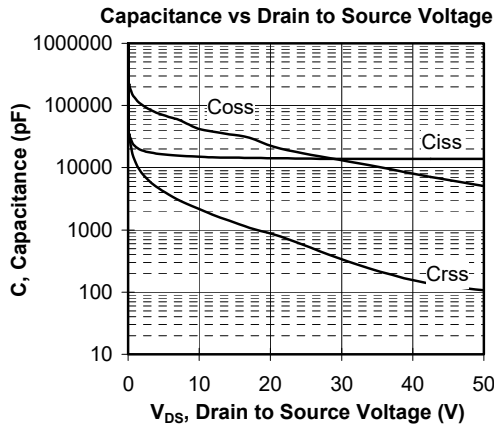
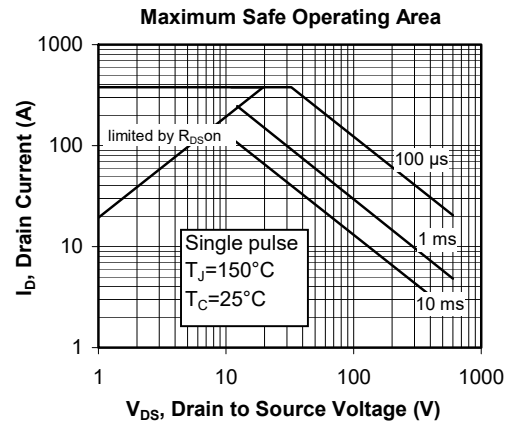
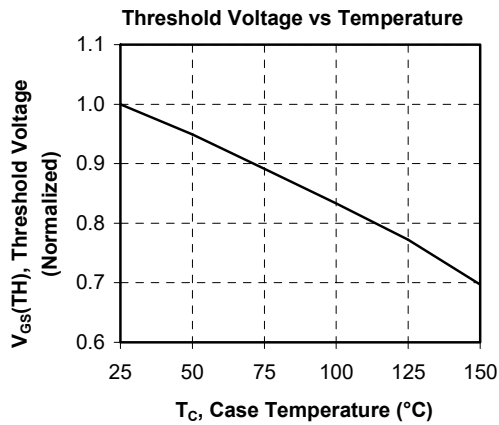
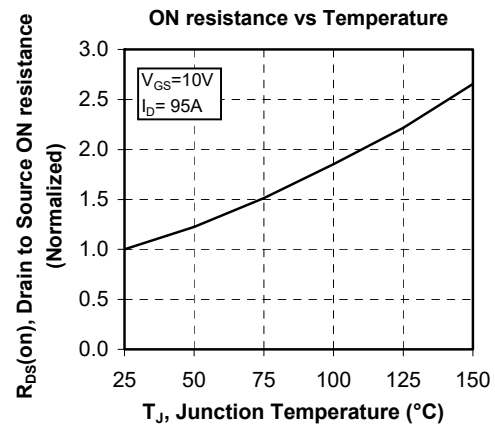
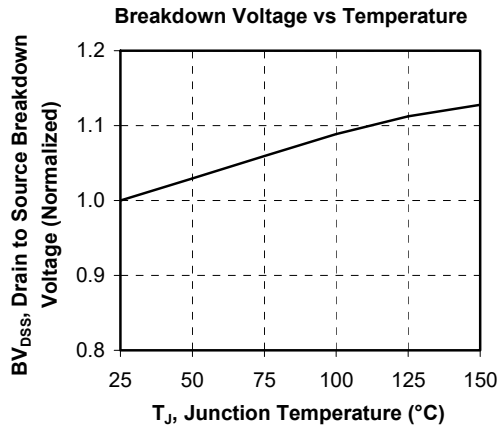
## Package outline (dimensions in mm)

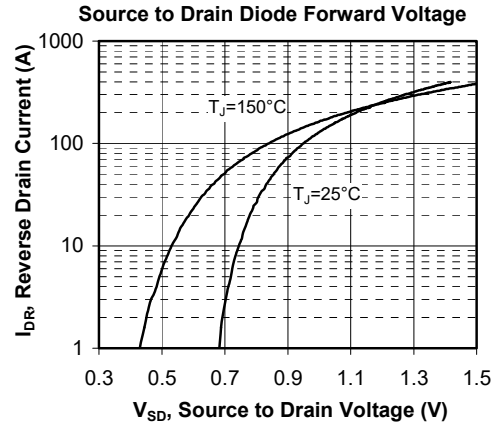
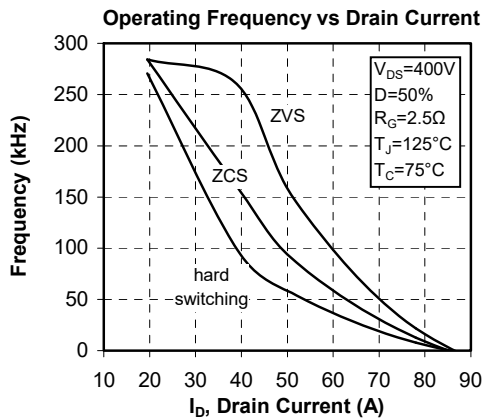
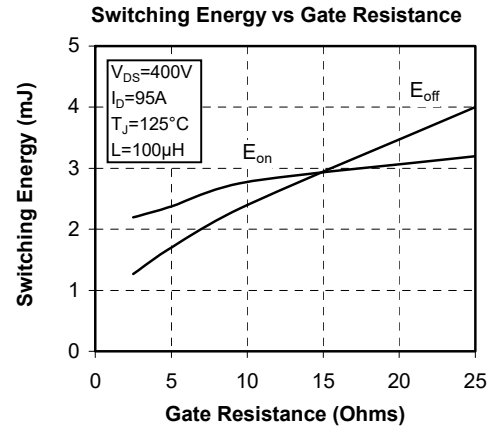
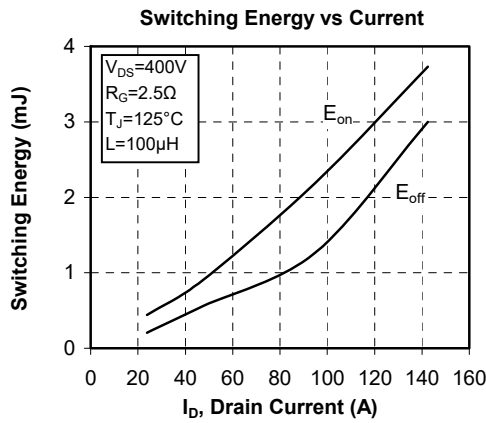
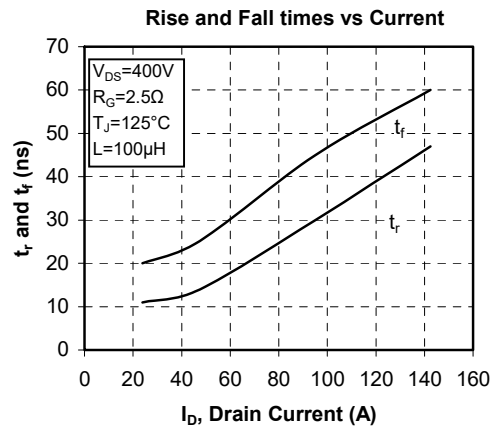
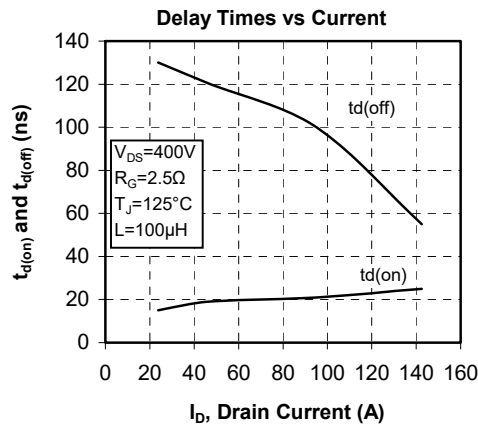


See application note 1906 - Mounting Instructions for SP3F Power Modules on [www.microsemi.com](http://www.microsemi.com)

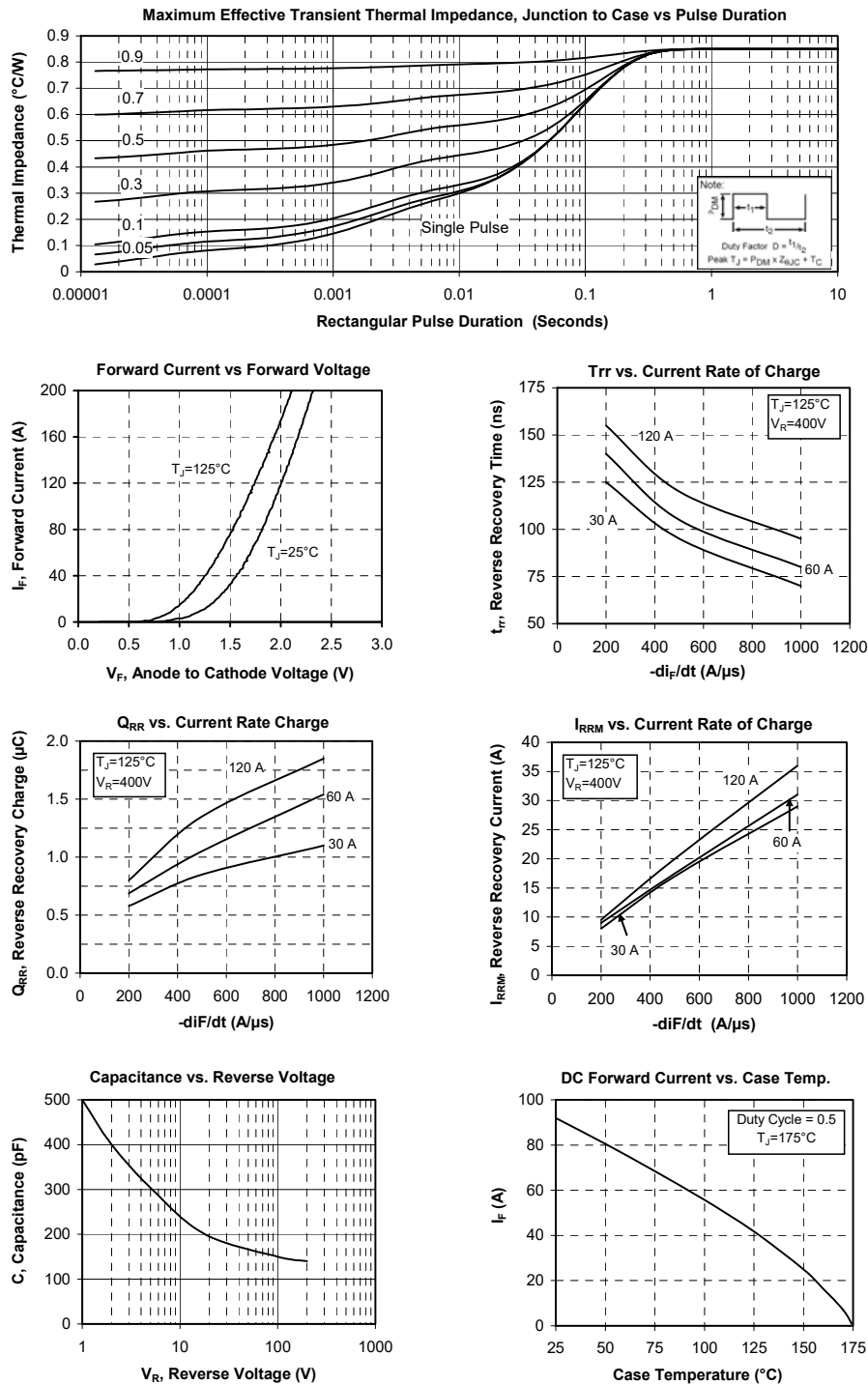
## Typical Super junction MOSFET Performance Curve







## Typical diode Performance Curve





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